

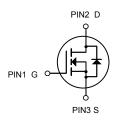
## **Description**

The AO3400-HXY uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

# D G SOT23-3L

#### **General Features**

 $V_{DS} = 30V, I_D = 5.8A$   $R_{DS(ON)} < 28m\Omega$  @  $V_{GS} = 10V$   $R_{DS(ON)} < 34m\Omega$  @  $V_{GS} = 4.5V$ 



#### N-Channel MOSFET

### **Application**

High power and current handing capability
Lead free product is acquired
Surface mount package
PWM applications
Load switch
Power management

## **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
AO3400-HXY	SOT23-3L	X0VX	3000PCS

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V <sub>DS</sub>	Drain-Source Voltage	30	V
V <sub>G</sub> s	Gate-Source Voltage	±12	V
ID	Drain Current-Continuous	5.8	Α
Ірм	Drain Current-Pulsed (Note 1)	30	Α
Po	Maximum Power Dissipation	1.4	W
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$ C
Reja	Thermal Resistance,Junction-to-Ambient (Note 2)	89	°C/W



# Electrical Characteristics (T<sub>A</sub>=25 <sup>°</sup>C unless otherwise noted)

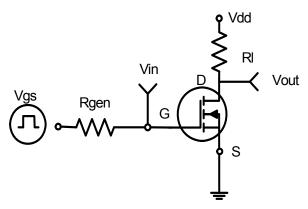
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	33	-	V
Zero Gate Voltage Drain Current	Ipss	$V_{DS}$ =30 $V$ , $V_{GS}$ =0 $V$	-	-	1	μA
Gate-Body Leakage Current	Igss	$V_{GS}$ =±12V, $V_{DS}$ =0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	$V_{DS}$ = $V_{GS}$ , $I_D$ =250 $\mu$ A	0.7	0.9	1.4	V
	RDS(ON)	V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	41	55	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	23	34	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =5.8A	-	21	28	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	10	-	-	S
Input Capacitance	Clss		-	825	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V,	-	100	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	78	-	PF
Turn-on Delay Time	td(on)		-	3.3	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =15V, $R_L$ =2.7 $\Omega$	-	4.8	-	nS
Turn-Off Delay Time	td(off)	V <sub>GS</sub> =10V,R <sub>GEN</sub> =3Ω -		26	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.6	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =4.5V	-	3.1	-	nC
Diode Forward Voltage (Note 3)	VsD	V <sub>GS</sub> =0V,I <sub>S</sub> =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.8	Α

#### Notes:

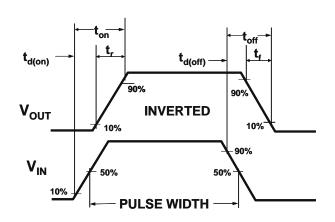
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



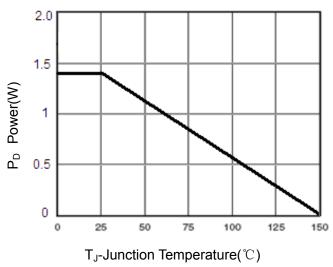
# **Typical Electrical and Thermal Characteristics**



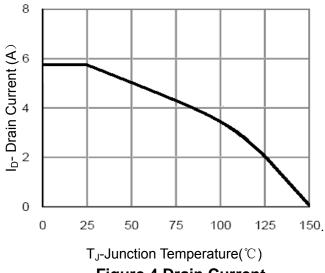
**Figure 1:Switching Test Circuit** 



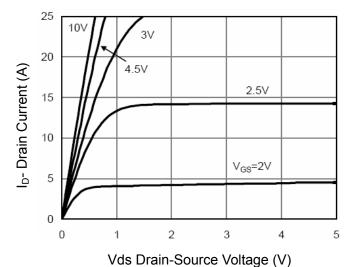
**Figure 2:Switching Waveforms** 



**Figure 3 Power Dissipation** 



**Figure 4 Drain Current** 



**Figure 5 Output Characteristics** 

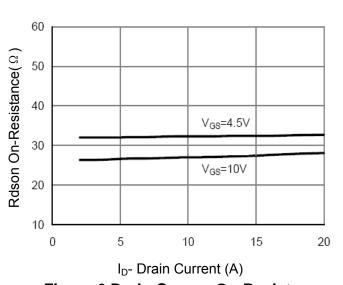
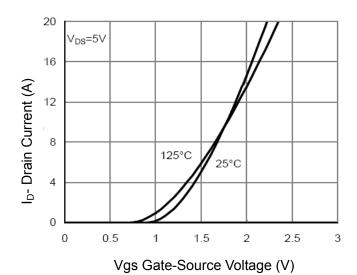


Figure 6 Drain-Source On-Resistance



**Figure 7 Transfer Characteristics** 

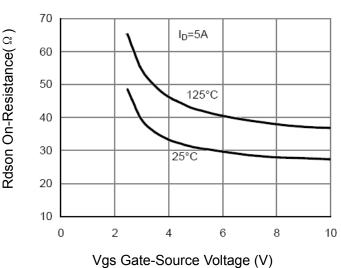


Figure 9 Rdson vs Vgs

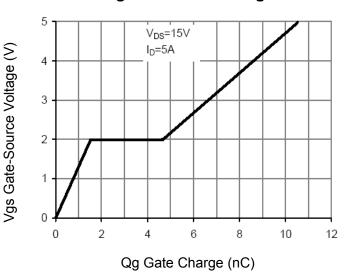


Figure 11 Gate Charge

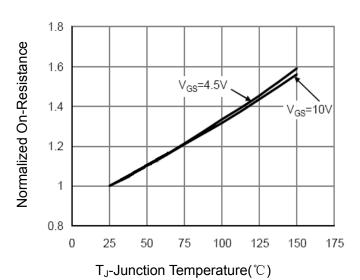


Figure 8 Drain-Source On-Resistance

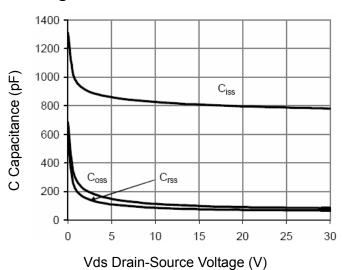


Figure 10 Capacitance vs Vds

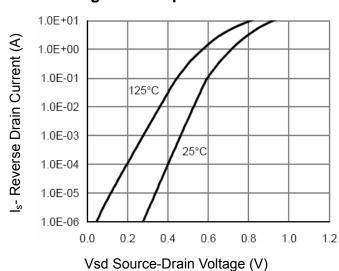


Figure 12 Source- Drain Diode Forward



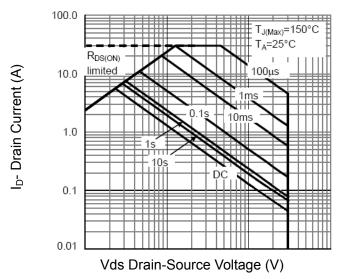
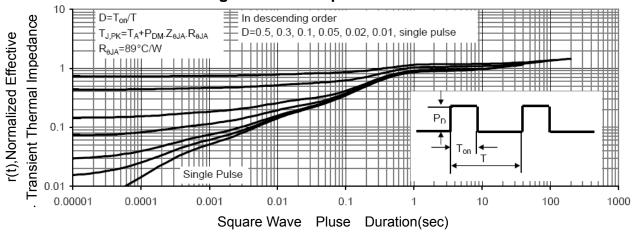


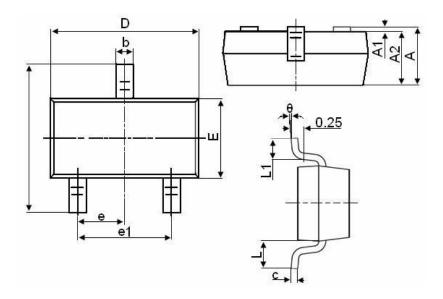
Figure 13 Safe Operation Area



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT23-3L Package Information**



Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
А	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.800	3.000		
E	1.500	1.700		
E1	2.650	2.950		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.600		
θ	0°	8°		



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